NSN 5961-00-081-0627

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Inclosure Material:
Metal
Overall Length:
0.320 inches
Terminal Length:
1.500 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
90.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
750.00 milliamperes source cutoff current and 750.00 milliamperes source cutoff current blank
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release3353 professional/industrial association specification

N/a

Shelf Life:

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Demilitarization:

No

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